

Kinetics of Photocatalytic Degradation of Formic Acid over Silica Composite Films Based on Polyoxometalates

Dan Feng LI, Yi Hang GUO, Chang Wen HU*, Li MAO, En Bo WANG

Institute of Polyoxometalate Chemistry, Northeast Normal University, Changchun 130024

Abstract: The composite films, $XW_{11}O_{39}^{n-}/SiO_2$, (X refers to Si, Ge or P, respectively) were prepared by tetraethoxysilane (TEOS) hydrolysis sol-gel method *via* spin-coating technique. Formation of the composite films is due to strong chemical reaction of organic silanol group with the surface oxygen atoms of $XW_{11}O_{39}^{n-}$, resulted in the saturation of the surface of the lacunary polyoxometalates (POMs). Therefore, the coordination structural model of the films was proposed. As for the films, retention of the primary Keggin structure was confirmed by UV-vis, FT-IR spectra and MAS NMR. The surface morphology of the films was characterized by SEM, indicating that the film surface is relatively uniform, and the layer thickness is in the range of 250~350 nm. Aqueous formic acid (FA) (0-20 mmol/L) was degraded into CO_2 and H_2O by irradiating the films in the near-UV area. The results show that all the films have photocatalytic activities and the degradation reaction follows Langmuir-Hinshelwood first order kinetics.

Keywords: Polyoxometalates, sol-gel, spin coating, composition film, photocatalysis, kinetics, formic acid.

So far, much work has been done on studying polyoxometalates (POMs) as photocatalysts for photo-oxidation of aqueous pollutants¹. However, most of such studies are concerned with homogeneous systems². As known, POMs have high water solubility, and it impedes their recovery and reuse. Recently, progress has been made for preparation of desolubilized POM materials³. Preparation of POM-containing films is a new way of immobilization of soluble POMs⁴. Among all the synthesis techniques, sol-gel method has obvious feasibility and easy control properties. Furthermore, to our knowledge, little reports have been made on the photocatalytic application of POMs-containing composite films. Here, we prepared $XW_{11}O_{39}^{n-}/SiO_2$ (XW_{11}/SiO_2) composite films by sol-gel method *via* spin-coating technique, and the photocatalytic behavior of the films was studied *via* degradation of FA under near-UV irradiation. The purpose of selecting FA as the model substance is that it is an organic pollutant existed in water or a stable intermediate found in photo-degraded processes. Photocatalytic tests showed that all the films have photocatalytic activity and the degradation reaction followed Langmuir-Hinshelwood first order kinetics.

*E-mail: huchw@nenu.edu.cn.

Experimental

XW₁₁/SiO₂ films were prepared as follows. 1.0 g of XW₁₁ was dissolved in water at room temperature (a little amount of dilute HNO₃ was added dropwise under vigorous stirring to increase the solubility of the XW₁₁). EtOH and TEOS were mixed, and the pH of the mixture was adjusted with dilute HNO₃. The acidic TEOS mixture was added to the solution of XW₁₁ and the pH should be changed when the different precursors were used. The reaction solution was stirred for *ca.* 1 h until a homogeneous silica sol was obtained. Then the quartz substrate was coated with the XW₁₁/SiO₂ sol. The films were dried under nitrogen atmosphere at room temperature. Finally the films were calcinated in vacuum at 120°C for 2 h for further fasten the silica network.

The photoreactor was designed with cylindrical quartz cell configuration and an internal light source surrounded by a quartz jacket, where aqueous FA solution completely surrounded the light source. Two slides (1.25×12×45 mm³) of the films were placed near the wall of the reactor. An external cooling coil was used to maintain the reaction temperature constant. The light source was a 125 W high pressure mercury lamp (HPML, output mainly at 313.2 nm). A general photocatalytic procedure was as follows. After the intensity of the light source became stable, the lamp was inserted into a fresh aqueous FA solution. The experiments were carried out at 25 ± 2°C with vigorous stirring.

Results and Discussion

The inorganic precursor XW₁₁ (X refers to Si, Ge or P) was introduced onto the quartz substrate in the form of hybrid silica sol XW₁₁/SiO₂. During TEOS hydrolysis sol-gel process, lacunary XW₁₁ cluster reacted with the products of TEOS hydrolysis [Si*(OSi)_{4-n}(OH)_n], led to the saturation of the XW₁₁ surface. Therefore, the coordination structural model of the films was proposed and shown in **Figure 1**. After formation of the composite films, retention of the structure integrity of the starting XW₁₁ (X = P, Si, Ge) was confirmed by UV-vis, FT-IR, ²⁹Si and ³¹P MAS NMR. Absorption at *ca.* 200 nm and 265 nm in UV spectroscopy was attributed to charge-transfer at W=O and W-O-W bonds, respectively. The UV data for the starting XW₁₁ are in agreement with that of the films, suggesting that the primary Keggin frameworks were retained

Figure 1 Proposed coordination model of the XW₁₁/SiO₂ films

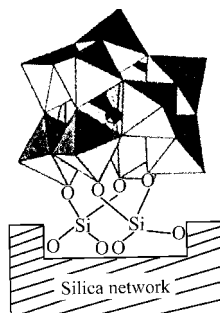


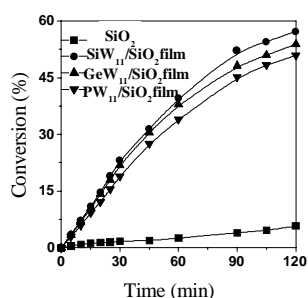
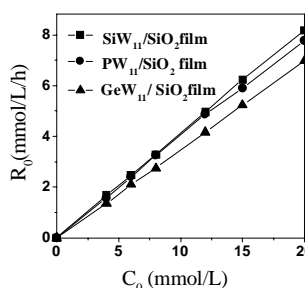
Table 1 Main IR data (cm^{-1}) of the starting XW_{11} and corresponding $\text{XW}_{11}/\text{SiO}_2$ ($\text{X} = \text{P, Si, Ge}$)

Sample	ν as (X-O)	ν as ($\text{W}=\text{O}_{\text{ter}}$)	ν as (W-O-W)
PW_{11}	1095, 1043	953	862, 833, 805, 730
$\text{PW}_{11}/\text{SiO}_2$ film	1079	953	870, 797, 672
SiW_{11}	995	950	882, 796, 728
$\text{SiW}_{11}/\text{SiO}_2$ film	1081	962	804, 697, 626
GeW_{11}	959	882	796, 697
$\text{GeW}_{11}/\text{SiO}_2$ film	956	881	792, 733, 676

intact after covalent bond with silica network was formed. FT-IR data of the starting XW_{11} and corresponding $\text{XW}_{11}/\text{SiO}_2$ films are shown in **Table 1**.

Pure XW_{11} display a characteristic infrared fingerprint in the region from *ca.* 1000 to 700 cm^{-1} , attributed to X-O in central XO_4 unit, W=O and W-O-W vibrations of XW_{11} respectively. In the band of the silica framework at 1080 cm^{-1} covered the vibration band of Si-O from central SiO_4 unit of SiW_{11} . The presence of the Si-O bond from central SiO_4 of SiW_{11} in the films was proved by ^{28}Si MAS NMR. The resonance at δ -94.31 ppm originated from central SiO_4 unit of SiW_{11} cluster, which is nearly the same with that of the parent SiW_{11} (δ -93.0 ppm), suggesting that Si-O in central SiO_4 existed in the hybrid materials. Therefore, we confirmed that after formation of the composite film the structure integrity of SiW_{11} was in retention. In the case of pure PW_{11} , the bands of P-O in central PO_4 were at 1095 and 1043 cm^{-1} in IR. However, only one band at 1079 cm^{-1} was observed for the $\text{PW}_{11}/\text{SiO}_2$ film. At the same time, ^{31}P MAS NMR showed one resonance signal at δ -13.5 ppm. These results showed that saturation of the cluster was obtained through grafting of siloxane group (determined ^{31}P MAS NMR resonance for PW_{12} and PW_{11} was at δ -12.9 and 10.4 ppm, respectively). W loadings estimated by ICP-AES for $\text{XW}_{11}/\text{SiO}_2$ films ($\text{X} = \text{P, Si, Ge}$) are 9.1%, 8.1%, and 7.6% respectively. In addition, experimental conditions may have effects on W loading. SEM images of $\text{XW}_{11}/\text{SiO}_2$ films indicate that the $\text{XW}_{11}/\text{SiO}_2$ sols were really coated on the surface of the quartz slide. The images also show that the as-synthesized films are relatively uniform and the thickness of the films is in the range of 250~350 nm.

The photocatalytic activity of the $\text{XW}_{11}/\text{SiO}_2$ films is due to XW_{11} . The photocatalytic activity of as-synthesized films was tested *via* degradation of an aqueous FA solution under irradiation in the near-UV area. In the presence of the films, stirring the aqueous FA solution in the dark for 120 min, the disappearance of FA is negligible. As for the silica support, *ca.* 6.5 % of FA disappeared under UV-irradiation for 120 min. However, apparent changes in the concentrations of FA were observed by irradiating the FA solutions in the presence of two slides of $\text{XW}_{11}/\text{SiO}_2$ films, *i.e.*, conversion of FA into CO_2 and H_2O was in the range of 50 %~60 % for different slides used (irradiation time was 120 min), as shown in **Figure 2** (Initial concentration of FA was 4 mmol/L). These results suggest that degradation of FA mainly originated from photoexcitation of the $\text{XW}_{11}/\text{SiO}_2$ films. Influence of initial FA concentration (C_0) on the initial FA disappearance rate (R_0) for photodegradation of FA solution was studied, and the results are shown in **Figure 3**. By changing C_0 in the range of 0-20 mmol/L, plot of R_0 vs C_0 exhibits three nearly straight lines. The value of k (the reaction rate constant) derived

Figure 2 Plot of Conversion vs Time**Figure 3** Initial rate (R_0) vs initial concentration

were 0.035, 0.029, 0.034 mmol/L/min respectively. The values of K (the adsorption equilibrium constant) are almost the same. The first order linear relationship can be explained in a Langmuir-Hinshelwood model (Eq.1):

$$R = -dC/dt = -kKC/(1 + KC) \quad (\text{Eq.1})$$

As for dilute solution, $KC \ll 1$, therefore, the above model can be expressed by (Eq.2):

$$R_0 = KkC_0 \quad (\text{Eq.2})$$

Indicating that the disappearance of FA follows a Langmuir-Hinshelwood first order kinetic law for initial FA concentration.

Conclusion

The method of preparation of the silica composite films based on lacunary Keggin-type POMs was proposed for the first time. The primary Keggin structures remained intact after formation of the films. Under UV-irradiation, all as-synthesized films exhibited photocatalytic activity on the degradation of aqueous FA. Little leakage of the POM from the silica matrix was due to chemical grafting of organosiloxane units to the surface of the lacunary POM. The films are more easily handled than that of the powder photocatalytic materials. The method exhibits the potential for practical applications.

Acknowledgments

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